


TRANSMITTAL

Electronic Version v1.1

Stylesheet Version v1.1.0

| Title of Invention | Method of Selective Deposition of Heavily Doped Epitaxial SiGe | |
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| Application Number : | 10/683937 |  |
| Date : | 2003-10-10 | |
| First Named Applicant: | Kim Yihwan | |
| Confirmation Number: | 2191 | |
| Attorney Docket Number: | AMAT8539TSGEPIRKK | |
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| Submitted By: Ya-Fen Chen Registered Number: 51,553 | | Elec. Sign. /Ya-Fen Chen/ Agent |
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| Documents being submitted: | Files |
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| us-ids | AMAT8539TSGEPIRKK-usidst.xml us-ids.dtd us-ids.xsl |
| Comments | |